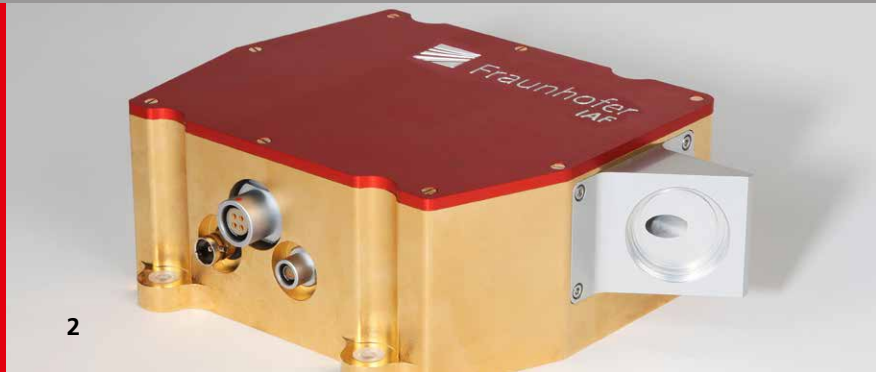


1

1 *Processed wafer with III-V compound semiconductor based laser chips.*

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2

2 *Infrared-emitting semiconductor laser module for high-resolution spectroscopy.*

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TAILORED SEMICONDUCTOR LASERS AND MODULES

Fraunhofer IAF specializes in the research and development of semiconductor lasers and laser modules emitting in the short-to-mid-wave infrared (1.9 – 3 μm , 4 – 11 μm). We provide our customers with customized laser sources for novel measurement and processing solutions for a wide range of applications.

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